

In the Claims:

1. **(original)** A process for the production of a strongly adherent metal coating on an inorganic or organic substrate, wherein
 - a) a low temperature plasma treatment, a corona discharge treatment or a flame treatment is carried out on the inorganic or organic substrate,
 - b) one or more photoinitiators or mixtures of photoinitiators with monomers or/and oligomers, containing at least one ethylenically unsaturated group, or solutions, suspensions or emulsions of the afore-mentioned substances, are applied to the inorganic or organic substrate,
 - c) the layer of step b) is optionally dried and is irradiated with electromagnetic waves; and
 - d) on the substrate so precoated with photoinitiator a metal, half-metal or metal oxide is deposited from the gasphase.
2. **(original)** A process according to claim 1, wherein step d) an irradiation with electromagnetic waves is carried out, either while depositing the metal, half-metal or metal oxide from the gasphase or after the deposition.
3. **(original)** A process according to claim 1, wherein the photoinitiator is a compound or combination of compounds from the classes of benzoines, benzil ketals, acetophenones, hydroxyalkylphenones, aminoalkylphenones, acylphosphine oxides, acylphosphine sulfides, acyloxyiminoketones, peroxy compounds, halogenated acetophenones, phenylglyoxylates, dimeric phenylglyoxalates, benzophenones, oximes and oxime esters, thioxanthenes, thiazolines, ferrocenes, coumarins, dinitrile compounds, titanocenes, sulfonium salts, iodonium salts, diazonium salts, onium salts, borates, triazines, bisimidazoles, polysilanes and dyes, and also corresponding coinitiators and/or sensitisers.
4. **(original)** A process according to claim 1, wherein the photoinitiator is a compound of formula I or Ia

wherein



wherein

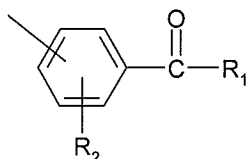
(IN) is a photoinitiator base structure;

A is a spacer group or a single bond;

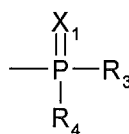
(RG) is hydrogen or at least one functional ethylenically unsaturated group; and

(RG') is a single bond or a divalent radical that contains at least one functional ethylenically unsaturated group, or is a trivalent radical.

5. (original) A process according to claim 4, wherein in the compound of formula I or Ia (IN) is a photoinitiator base structure of formula (II) or (III)

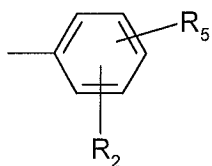


(II),



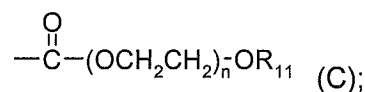
(III),

R₁ is a group (A), (B), (C) or (III)



(A),

-CR₆R₇R₈ (B)



(C);

n is a number from 0 to 6;

R₂ is hydrogen, C₁-C₁₂alkyl, halogen, the group (RG)-A- or, when R₁ is a group (A), two radicals

R₂ in the ortho-position to the carbonyl group may also together be -S- or ;

R₃ and R₄ are each independently of the other C₁-C₆alkyl, C₁-C₆alkanoyl, phenyl or benzoyl, the radicals phenyl and benzoyl each being unsubstituted or substituted by halogen, C₁-C₆alkyl, C₁-C₆alkylthio or by C₁-C₆alkoxy;

R₅ is hydrogen, halogen, C₁-C₁₂alkyl or C₁-C₁₂alkoxy or the group (RG)-A- ;

R₆ is OR₉ or N(R₉)₂ or is , , , or SO₂R₉;

R₇ and R₈ are each independently of the other hydrogen, C₁-C₁₂alkyl, C₂-C₁₂alkenyl, C₁-C₁₂alkoxy, phenyl or benzyl or R₇ and R₈ together are C₂-C₆alkylene;

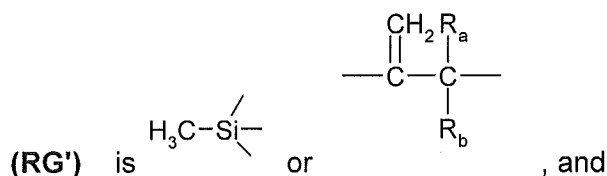
R₉ is hydrogen, C₁-C₆alkyl or C₁-C₆alkanoyl;

R₁₀ is hydrogen, C₁-C₁₂alkyl or phenyl;

R₁₁ is C₁-C₄alkyl or ; and

X₁ is oxygen or sulfur.

6. **(previously presented)** A process according to claim 5, wherein in the compound of formula I or Ia
(RG) is $R_cR_bC=CR_a$;



R_a , R_b and R_c are each independently of the other hydrogen or C_1 - C_6 alkyl.

7. **(previously presented)** A process according to claim 1, wherein the photoinitiator(s) or mixtures thereof with monomers or oligomers are used in combination with one or more liquids in the form of solutions, suspensions and emulsions.

8. **(previously presented)** A process according to claim 1, wherein an inert gas or a mixture of inert gas with reactive gas is used as the plasma gas.

9. **(original)** A process according to claim 8, wherein air, H_2 , CO_2 , He, Ar, Kr, Xe, N_2 , O_2 or H_2O are used singly or in the form of a mixture.

10. **(previously presented)** A process according to claim 1, wherein the photoinitiator layer applied has a layer thickness of up to 500 nm.

11. **(original)** A process according to claim 1, wherein process step b) is carried out immediately after process step a) or within 24 hours after process step a).

12. **(previously presented)** A process according to claim 1, wherein the concentration of photoinitiator or photoinitiators in process step b) is from 0.01 to 99.5 %.

13. **(original)** A process according to claim 1, wherein process step c) is carried out immediately after process step b) or within 24 hours after process step b).

14. **(original)** A process according to claim 1, wherein drying in process step c) is effected in ovens, with hot gases, heated rollers or IR or microwave radiators or by absorption.

15. **(previously presented)** A process according to claim 1, wherein irradiation in process step c) and/or d) is effected with a source that emits electromagnetic waves of wavelengths in the range from 200 nm to 700 nm, or by electron beams.

16-18. **(cancelled)**

19. **(withdrawn)** A strongly adherent coating obtained by a process according to claim 1.

20. **(withdrawn)** A strongly adherent coating obtained by a process according to claim 2.

21. **(previously presented)** A process according to claim 2, wherein an inert gas or a mixture of inert gas with reactive gas is used as the plasma gas.